

# 8-bit μP-compatible D/A converter

5018

## FEATURES

- 8-bit resolution
- Input latches
- Low-loading data inputs
- On-chip voltage reference
- Output buffer amplifier
- Accurate to  $\pm 1/2$  LSB (0.19%)
- Monotonic to 8 bits
- Amplifier and reference both short-circuit protected
- Compatible with 8085, 68000 and many other μPs

## APPLICATIONS

- Precision 8-bit D/A converters
- A/D converters
- Programmable power supplies
- Test equipment
- Measuring instruments
- Analog-digital multiplication

## DESCRIPTION

The 5018 is a complete 8-bit digital-to-analog converter subsystem on one monolithic chip. The data inputs have input latches, controlled by a latch enable pin. The data and latch enable inputs are ultra-low loading for easy interfacing with all logic systems. The latches appear transparent when the LE input is in the low state. When LE goes high, the input data present at the moment of transition is latched and retained until LE again goes low. This feature allows easy compatibility with most microprocessors.

The chip also comprises a stable voltage reference (5V nominal) and high slew rate buffer amplifier. The voltage reference may be externally trimmed with a potentiometer for easy adjustment of full scale, while maintaining a low temperature coefficient.

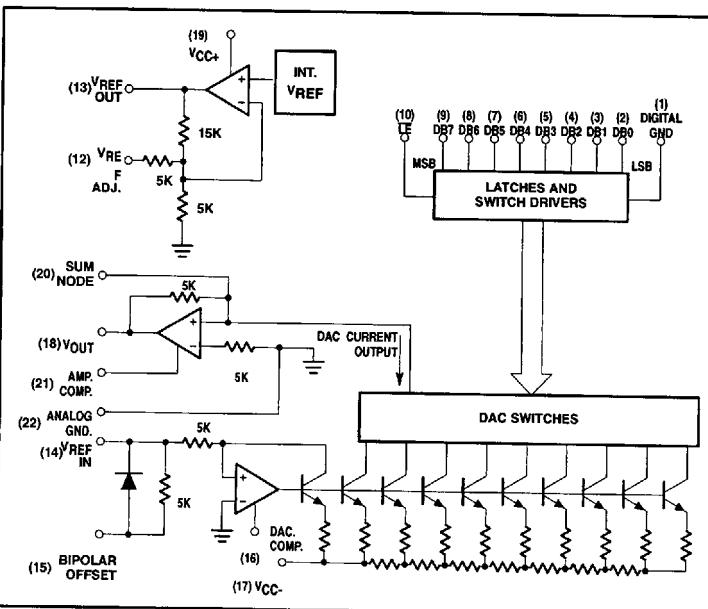
The output of the buffer amplifier may be offset so as to provide bipolar as well as unipolar operation.

## ORDERING INFORMATION

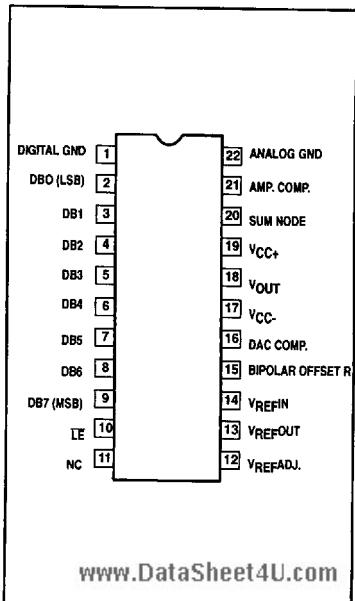
DESCRIPTION	ORDER CODE	PACKAGE DESIGNATOR
22-Pin Ceramic DIP	5018/BWA	GDIP1-T22

\* MIL-STD 1835 or Appendix A of 1995 Military Data Handbook

## BLOCK DIAGRAM



## PIN CONFIGURATION



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## ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER				RATING <sup>1</sup>	UNIT
V <sub>CC+</sub>	Positive supply voltage				18	V
V <sub>CC-</sub>	Negative supply voltage				-18	V
V <sub>I</sub>	Logic input voltage				0 to 18	V
V <sub>REFIN</sub>	Voltage at V <sub>REF</sub> input				12	V
V <sub>REFADJ</sub>	Voltage at V <sub>REF</sub> adjust				0 to V <sub>REF</sub>	V
V <sub>SUM</sub>	Voltage at sum node				12	V
I <sub>REFSC</sub>	Short-circuit current to ground at V <sub>REFOUT</sub>				Continuous	
I <sub>OUTSC</sub>	Short-circuit current to ground or either supply at V <sub>OUT</sub>				Continuous	
P <sub>D</sub>	Power dissipation				1000	mW

## DC ELECTRICAL CHARACTERISTICS

V<sub>CC+</sub> = +15V, V<sub>CC-</sub> = -15V, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS <sup>2</sup>	T <sub>amb</sub> = +25°C			T <sub>amb</sub> = -55°C, +125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
ΔFS	Resolution Monotonicity Relative accuracy		8 8	8 8	8 ±0.19	8		8 8 ±0.19	Bits Bits %FS
V <sub>CC+</sub> V <sub>CC-</sub>	Positive supply voltage Negative supply voltage	+11.4 -11.4	+15 -15			+11.4 -11.4	+15 -15		V V
V <sub>IH</sub> V <sub>IL</sub>	Logic "1" input voltage Logic "0" input voltage	Pin 1 = GND Pin 1 = GND	2.0		0.8	2.0		0.8	V V
I <sub>IH</sub>	Logic "1" input current	Pin 1 = GND, 2V < V <sub>I</sub> < 18V		0.1	10			10	µA
I <sub>IL</sub>	Logic "0" input current	Pin 1 = GND, -5V < V <sub>I</sub> < 0.8V		-2.0	-10			-10	µA
V <sub>FS</sub>	Full scale output voltage	Unipolar operation V <sub>REF IN</sub> = 5.000V	9.50	9.961	10.50				V
V <sub>FS</sub>	Full scale output voltage	Bipolar operation V <sub>REF IN</sub> = 5.000V	4.5 -5.25	4.961 -5.000	5.5 -4.75				V
V <sub>ZS</sub>	Zero scale voltage	Bipolar operation V <sub>REF IN</sub> = 5.000V	-30	5	+30	-30		+30	mV
I <sub>SC</sub>	Output short circuit current	V <sub>O</sub> = 0V		15	40				mA
PSR+(out)	Output power supply rejection (+)	V <sub>CC-</sub> = -15V, 13.5V ≤ V <sub>CC+</sub> ≤ 16.5V external V <sub>REF IN</sub> = 5.000V		0.001	0.01			0.01	%FS/ %VS
PSR-(out)	Output power supply rejection (-)	V <sub>CC+</sub> = -15V, -13.5V ≤ V <sub>CC-</sub> ≤ -16.5V, external V <sub>REF IN</sub> = 5.000V		0.001	0.01			0.01	%FS/ %VS
TCFS	Full scale temperature coefficient	V <sub>REF IN</sub> = 5.000V					20		ppm/°C
TCzs	Zero scale temperature coefficient						5		ppm/°C
I <sub>REF</sub> I <sub>REFSC</sub>	Reference output current <sup>9</sup> Reference short circuit current	V <sub>REF OUT</sub> = 0V		15	3 30				mA mA
PSR+(REF )	Reference power supply rejection (+)	V <sub>CC-</sub> = -15V 13.5V ≤ V <sub>CC+</sub> ≤ 16.5V, I <sub>REF</sub> = 1.0mA		0.003	0.01			0.01	%FR/%VS
PSR-(REF)	Reference power supply rejection (-)	V <sub>CC+</sub> = -15V, -13.5V ≤ V <sub>CC-</sub> ≤ 16.5V, I <sub>REF</sub> = 1.0 mA		0.003	0.01			0.01	%FR/%VS
V <sub>REF</sub>	Reference voltage	I <sub>REF</sub> = 1.0mA	4.9	5.0	5.25				V

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## DC ELECTRICAL CHARACTERISTICS (Continued)

SYMBOL	PARAMETER	TEST CONDITIONS <sup>2</sup>	T <sub>amb</sub> = +25°C			T <sub>amb</sub> = -55°C, +125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
ΔY <sub>REF</sub> /ΔT	Reference voltage temperature coefficient	I <sub>REF</sub> = 1.0mA						60	ppm/°C
Z <sub>IN</sub>	DAC V <sub>REF</sub> IN input impedance	I <sub>REF</sub> = 1.0mA	4.15	5.0	5.85				kΩ
I <sub>CC+</sub> I <sub>CC-</sub>	Positive supply current Negative supply current	V <sub>CC+</sub> = 15V V <sub>CC-</sub> = -15V		7 -10	14 -15			14 -15	mA mA
P <sub>D</sub>	Power dissipation	I <sub>REF</sub> = 1.0mA, V <sub>CC</sub> = ±15V		255	435			435	mW

## AC ELECTRICAL CHARACTERISTICS

V<sub>CC+</sub> = +15V, V<sub>CC-</sub> = -15V, unless otherwise specified.

SYMBOL	PARAMETER	TO	FROM	TEST CONDITIONS <a href="http://www.DataSheet4U.com">www.DataSheet4U.com</a>	T <sub>amb</sub> = +25°C			T <sub>amb</sub> = 55°C, +125°C			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
t <sub>SLH</sub>	Setting time <sup>4</sup>	± 1/2 LSB	Input	All bits low-to-high <sup>3</sup>		1.8					μs
t <sub>SHL</sub>	Setting time <sup>5</sup>	± 1/2 LSB	Input	All bits high-to-low		2.3					μs
t <sub>PLH</sub> t <sub>PHL</sub> t <sub>PLSB</sub>	Propagation delay <sup>4</sup> Propagation delay <sup>5</sup> Propagation delay <sup>4-5</sup>	Output Output Output	Input Input Input	All bits switched low-to-high All bits switched high-to-low 1 LSB change <sup>3-4</sup>		300 150 150					ns ns ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay <sup>6</sup> Propagation delay <sup>7</sup>	Output Output	LE LE	Low-to-High transition High-to-Low transition		300 150					ns ns
t <sub>S</sub> t <sub>H</sub> t <sub>PW</sub>	Setup time <sup>3,8</sup> Hold time <sup>3,8</sup> Latch enable pulse width <sup>3,8</sup>	LE Input	Input LE		100 50 150						ns ns ns

## NOTES:

1. Operation beyond limits in the table may impair the useful life of the device.
2. Refer to Figure 1.
3. Refer to Figure 2.
4. See Figure 5.
5. See Figure 6.
6. See Figure 7.
7. See Figure 8.
8. See Figure 9.
9. For reference currents > 3mA, use of an external buffer is required.

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## TEST CONFIGURATIONS AND WAVEFORM DEFINITIONS

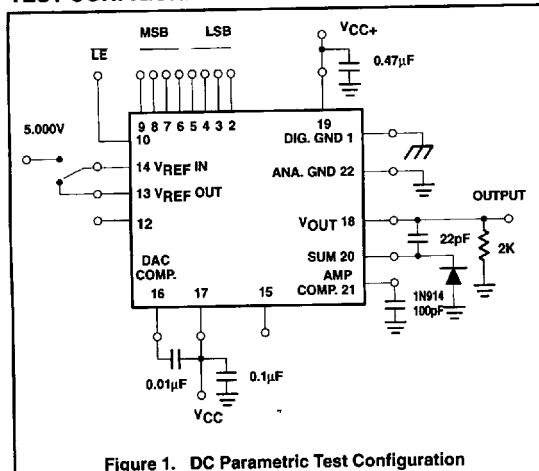


Figure 1. DC Parametric Test Configuration

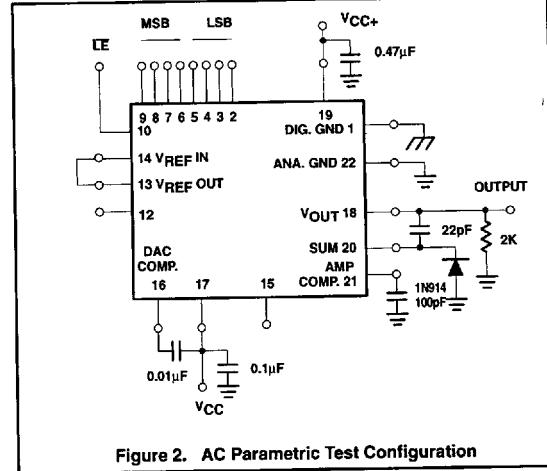


Figure 2. AC Parametric Test Configuration

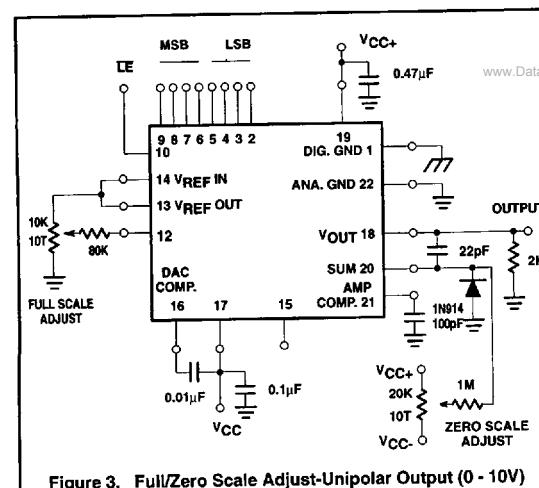


Figure 3. Full/Zero Scale Adjust-Unipolar Output (0 - 10V)

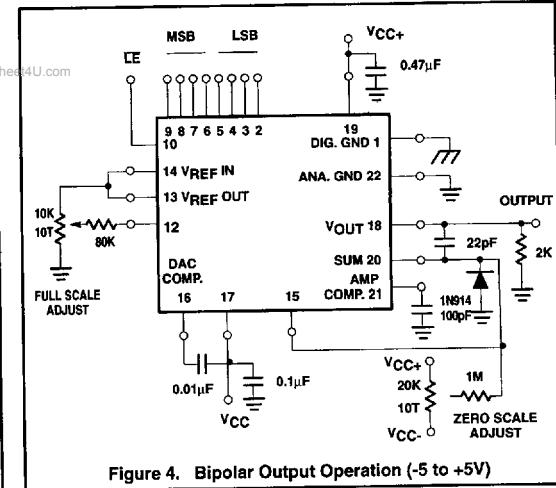


Figure 4. Bipolar Output Operation (-5 to +5V)

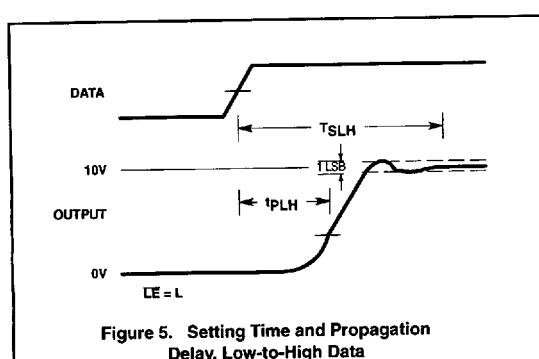


Figure 5. Setting Time and Propagation Delay, Low-to-High Data

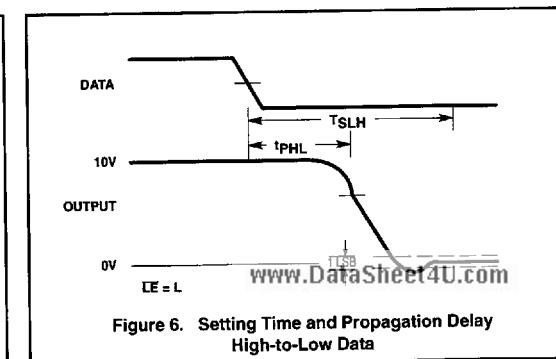


Figure 6. Setting Time and Propagation Delay High-to-Low Data

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## TEST WAVEFORM DEFINITIONS

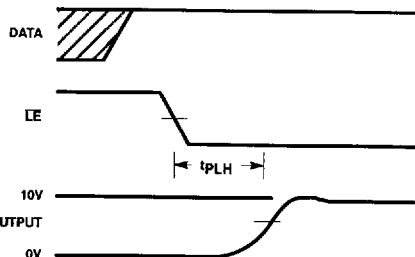


Figure 7. Propagation Delay, Latch Enable to Output

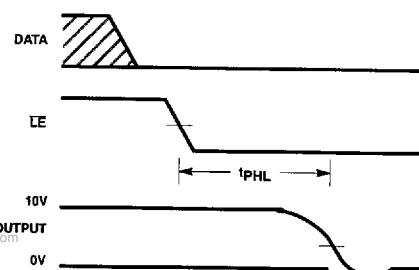


Figure 8. Propagation Delay, Latch Enable to Output

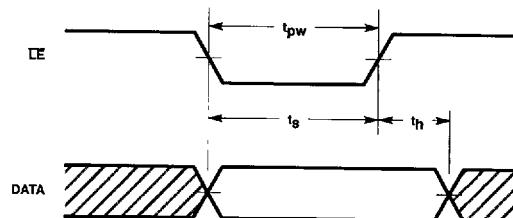


Figure 9. Latch Enable Pulse Width, Setup and Hold Times

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